FORM PTO-1449 LIST OF PATENTS AND APPLICANT'S INFORMATION DISCLOSURE STATEMENT ATTORNEY DOCKET NO.: 782270 PI SERIAL NO.: 10/736,859 FILING DATE: December 16, 2003 JAN 2 0 2004 APPLICANT: GROUP: Unknown Yao F TRADEMAN U.S. PATENT DOCUMENTS REFERENCE DESIGNATION BXAMINER DOCUMENT DATE NAME CLASS SUB FILING IF APPROPRIATE INITIALS NUMBER CLASS AA AB AC AD ΑE AF AG POREIGN PATENT DOCUMENTS DOCUMENT DATE COUNTRY CLASS SUBCLASS TRANSLATION NUMBER Yes -- No AM AN AO AP ΑQ OTHER ART (Including Author, Title, Date, Pertinent Pages, etc.) Yao, Jie et al., Bandwidth Simulations Of 10 Gb/s Avalanche Photodiodes, IEEE, pp. 699 - 700. R А DATE CONSIDERED: EXAMINER: EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609;
• Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.

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